

February 1992 Revised June 2001

#### 74LVQ573

## Low Voltage Octal Latch with 3-STATE Outputs

#### **General Description**

The LVQ573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable  $(\overline{\text{OE}})$  inputs. The LVQ573 is functionally identical to the LVQ373 but with inputs and outputs on opposite sides of the package.

#### **Features**

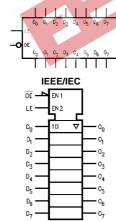
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ, and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- $\blacksquare$  Guaranteed incident wave switching into 75 $\Omega$
- 4 kV minimum ESD immunity

#### **Ordering Code:**

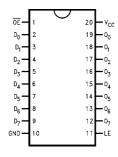
Order Number	Package Number	Package Description					
74LVQ573SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide					
74LVQ573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74LVQ573QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide					

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code

#### **Logic Symbols**



#### **Connection Diagram**



#### **Pin Descriptions**

Pin Names	Description				
D <sub>0</sub> –D <sub>7</sub>	Data Inputs				
LE OE	Latch Enable Input				
OE	3-STATE Output Enable Input				
O <sub>0</sub> -O <sub>7</sub>	3-STATE Latch Outputs				

### **Truth Table**

	Outputs		
OE	LE	D	O <sub>n</sub>
L	Н	Н	Н
L	Н	L	L
L	L	Х	$O_0$
Н	X	Х	Z
11 1110111111			

H = HIGH Voltage Z = High Impedance L = LOW Voltag X = Immaterial

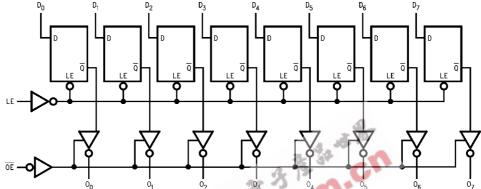
 $O_0$  = Previous  $O_0$  before HIGH-to-LOW transition of Latch Enable

#### **Functional Description**

The LVQ573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the  $D_{\rm n}$  inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW the latches store the information that was present on the

D-type inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable  $\overline{(\text{OE})}$  input. When  $\overline{\text{OE}}$  is LOW, the buffers are enabled. When  $\overline{\text{OE}}$  is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

#### **Logic Diagram**



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays

#### **Absolute Maximum Ratings**(Note 1)

Supply Voltage (V<sub>CC</sub>) -0.5V to +7.0V

DC Input Diode Current (I<sub>IK</sub>)

 $V_{I} = -0.5V$ -20 mA  $V_I = V_{CC} + 0.5V$ +20 mA DC Input Voltage (V<sub>I</sub>) -0.5V to  $V_{CC} + 0.5V$ 

DC Output Diode Current (I<sub>OK</sub>)

 $V_{O} = -0.5V$ -20 mA +20 mA  $V_O = V_{CC} + 0.5V$ 

DC Output Voltage (V<sub>O</sub>)  $-0.5\mbox{V}$  to  $\mbox{V}_{\mbox{CC}} + 0.5\mbox{V}$ 

DC Output Source

or Sink Current (I<sub>O</sub>) ±50 mA

DC  $V_{CC}$  or Ground

Current (I<sub>CC</sub> or I<sub>GND</sub>) ±400 mA Storage Temperature (T<sub>STG</sub>) -65°C to +150°C

#### **Recommended Operating** Conditions (Note 2)

Supply Voltage (V<sub>CC</sub>) 2.0V to 3.6V Input Voltage (V<sub>I</sub>) 0V to V<sub>CC</sub> Output Voltage (V<sub>O</sub>) 0V to V<sub>CC</sub> -40°C to +85°C Operating Temperature (T<sub>A</sub>)

Minimum Input Edge Rate  $(\Delta V/\Delta t)$ 

 $V_{\mbox{\footnotesize{IN}}}$  from 0.8V to 2.0V

V<sub>CC</sub> @ 3.0V 125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical . Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

#### **DC Electrical Characteristics**

	ch-Up Source or Current	±300 mA			A The			
DC E	lectrical Characteri	stics			$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ Units Conditions			
Symbol Parameter		V <sub>CC</sub> T <sub>A</sub> = +25°C			°C T <sub>A</sub> = −40°C to +85°C Guaranteed Limits		Conditions	
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V	
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	٧	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> – 0.1V	
V <sub>OH</sub>	Minimum High Level	3.0	2.99	2.9	2.9	V	I <sub>OUT</sub> = -50 μA	
	Output Voltage	3.0		2.58	2.48	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OH} = -12 \text{ mA}$	
V <sub>OL</sub>	Maximum Low Level	3.0	0.002	0.1	0.1	V	I <sub>OUT</sub> = 50 μA	
	Output Voltage	3.0		0.36	0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OL} = 12 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}$ , GND	
I <sub>OLD</sub>	Minimum Dynamic	3.6			36	mA	V <sub>OLD</sub> = 0.8 V <sub>Max</sub> (Note 5)	
I <sub>OHD</sub>	Output Current (Note 4)	3.6			-25	mA	V <sub>OHD</sub> = 2.0V V <sub>Min</sub> (Note 5)	
lcc	Maximum Quiescent Supply Current	3.6		4.0	40.0	μА	$V_{IN} = V_{CC}$ or GND	
l <sub>OZ</sub>	3-STATE Leakage Current	3.6		±0.25	±2.5	μА	$\begin{aligned} &V_{I}\left(\overline{OE}\right) = V_{IL}, \ V_{IH} \\ &V_{I} = V_{CC}, \ GND \\ &V_{O} = V_{CC}, \ GND \end{aligned}$	
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.4	0.8		V	(Note 6)(Note 7)	
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.4	-0.8		V	(Note 6)(Note 7)	
V <sub>IHD</sub>	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Note 6)(Note 8)	
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Note 6)(Note 8)	

Note 3: All outputs loaded: thresholds on input associated with output under test.

 $\textbf{Note 8:} \ \text{Max number of Data Inputs (n) switching. (n-1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to$  $(V_{IHD})$ , f = 1 MHz.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as  $75\Omega$  for commercial temperature range is guaranteed for.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

# **AC Electrical Characteristics**

	Parameter		$T_A = +25^{\circ}C$ $C_L = 50 \text{ pF}$			$T_A = -40$ °C to +85°C $C_L = 50$ pF		Units
Symbol		V <sub>CC</sub>						
		(V)	Min	Тур	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	2.7	2.5	10.2	14.8	2.5	16.0	no
t <sub>PLH</sub>	D <sub>n</sub> to O <sub>n</sub>	$3.3\pm0.3$	2.5	8.5	10.5	2.5	11.0	ns
t <sub>PLH</sub>	Propagation Delay	2.7	2.5	10.2	16.9	2.5	18.0	
t <sub>PHL</sub>	LE to O <sub>n</sub>	$3.3\pm0.3$	2.5	8.5	12.0	2.5	12.5	ns
t <sub>PZL</sub>	Output Enable Time	2.7	2.5	10.2	18.3	2.5	19.0	
t <sub>PZH</sub>		$3.3\pm0.3$	2.5	8.5	13.0	2.5	13.5	ns
t <sub>PHZ</sub>	Output Disable Time	2.7	1.0	10.8	20.4	1.0	21.0	no
$t_{PLZ}$		$3.3\pm0.3$	1.0	9.0	14.5	1.0	15.0	ns
t <sub>OSHL</sub>	Output to Output Skew (Note 9)	2.7		1.0	1.5		1.5	ns
t <sub>OSLH</sub>	D <sub>n</sub> to O <sub>n</sub>	$3.3\pm0.3$		1.0	1.5		1.5	115

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

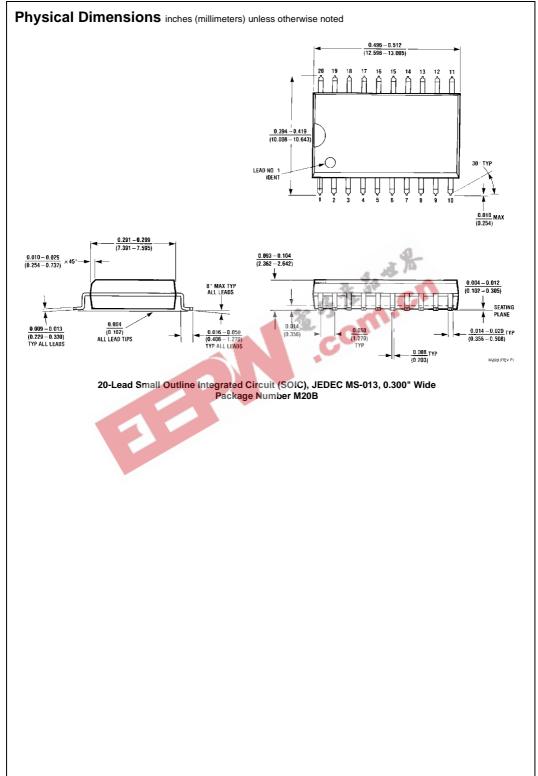
# **AC Operating Requirements**

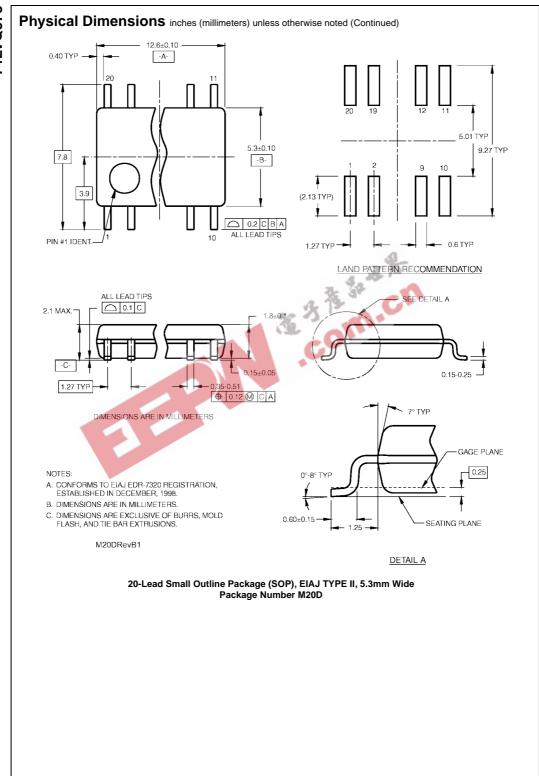
Symbol	Parameter	V <sub>CC</sub>	$C_L = 50 \text{ pF}$ $C_L = 50 \text{ pF}$			Units
-	Setup Time, HIGH or LOW	(V) 2.7	Тур	Guar <b>a</b> nt	eed Minimum 4.5	
t <sub>S</sub>	D <sub>n</sub> to LE	$3.3 \pm 0.3$	0	<b>3</b> .0	3.0	ns
t <sub>H</sub>	Hold Time, HIGH or LOW	2.7	0	1.5	1.5	ns
	D <sub>n</sub> to LE	$3.3\pm0.3$	0	1.5	1.5	115
t <sub>W</sub>	LE Pulse Width, HIGH	2.7	2.4	5.0	6.0	ns
		$3.3 \pm 0.3$	2.0	4.0	4.0	115

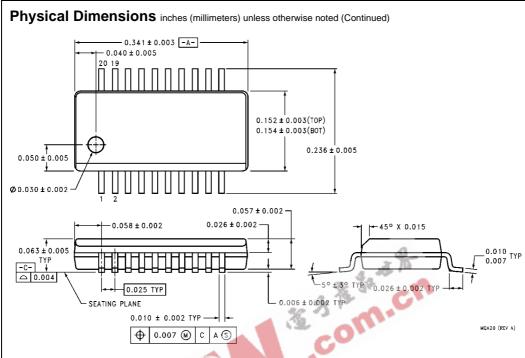
## Capacitance

Symbol	Parameter	Тур	Units	Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = Open
C <sub>PD</sub> (Note 10)	Power Dissipation Capacitance	37	pF	V <sub>CC</sub> = 3.3V

Note 10: C<sub>PD</sub> is measured at 10 MHz.







20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide Package Number MQA20

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